



FPAB30BH60 PFC SPM® 3 Series for 1-Phase Boost PFC

Features

- Low Thermal Resistance Thanks to Al₂O₃-DBC Substrate
- 600 V - 30 A 1-Phase Boost PFC Including A Drive IC for Gate Driving and Protection
- Built-In NTC Thermistor for Monitoring Over-Temperature
- Typical Switching Frequency of 20 kHz
- Isolation Rating of 2500 Vrms/min.

Applications

1-Phase Boost PFC Converter for Air Conditioner

General Description

FPAB30BH60 Is A PFC SPM 3 Series for 1-Phase Boost PFC (Power Factor Correction) that Fairchild Has Newly Developed for Mid-Power Applications such as Air Conditioners. It Combines Optimized Circuit Protections and A Drive IC Matched to High Frequency Switching IGBT. The System Reliability Is Further Enhanced by The Integrated Under-Voltage Lock-Out and Over-Current Protection Function.

Related Source

- [Will Be Released](#)

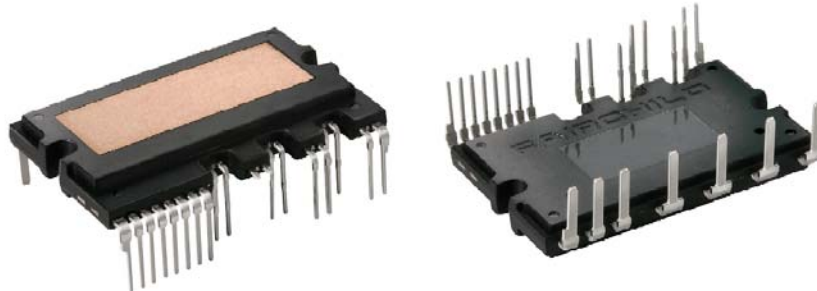


Fig. 1. Package Overview

Package Marking & Ordering Information

| Device Marking | Device | Package | Packing Type | Reel Size | Tape Width | Quantity |
|----------------|------------|-----------|--------------|-----------|------------|----------|
| FPAB30BH60 | FPAB30BH60 | SPMIA-027 | RAIL | - | - | 10 |

Integrated Power Functions

- PFC converter for single-phase AC/DC power conversion (Please refer to Fig. 3)

Integrated Drive, Protection and System Control Functions

- For IGBTs : Gate drive circuit, Over Current(OC) protection, Control supply circuit Under-Voltage(UV) protection
- Fault signal : Corresponding to OC and UV fault
- Built-in thermistor: Over-temperature monitoring
- Input interface : Active-high interface, can work with 3.3 / 5 V Logic, Schmitt trigger input

Pin Configuration

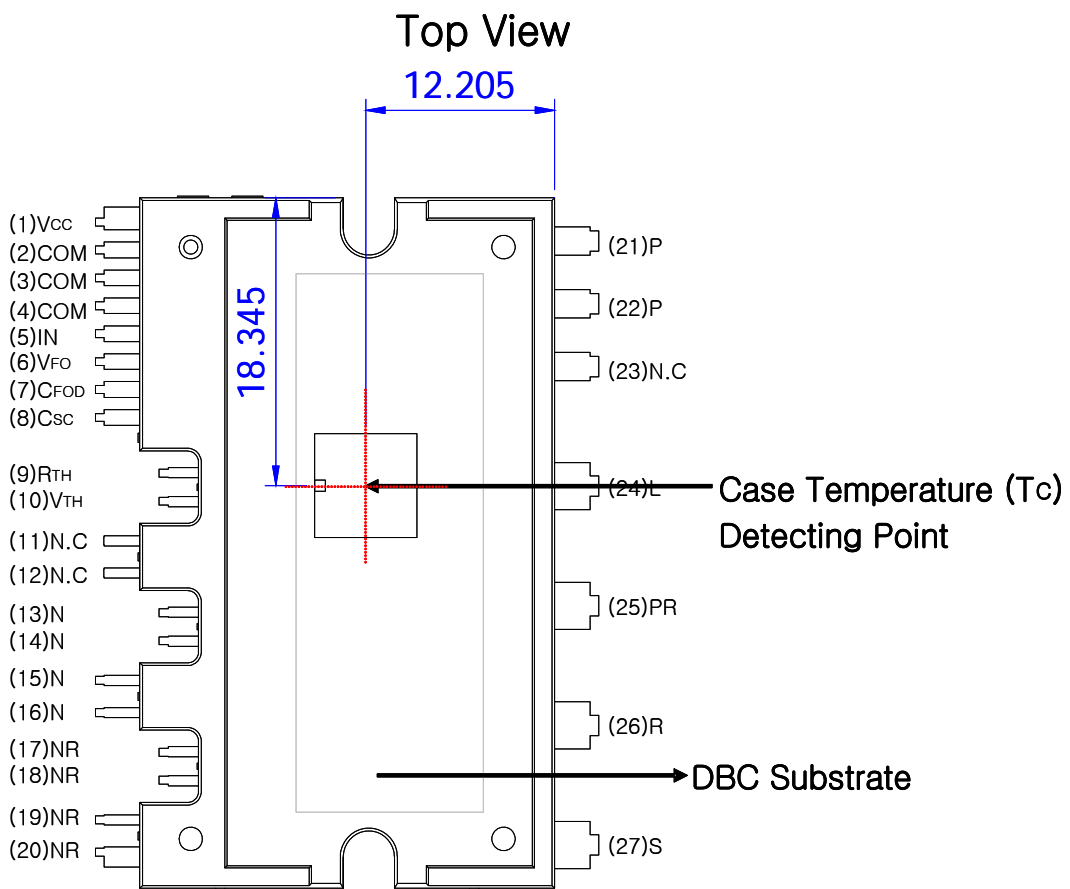


Fig. 2.

Pin Descriptions

| Pin Number | Pin Name | Pin Description |
|------------|-------------------|--|
| 1 | V _{CC} | Common Bias Voltage for IC and IGBTs Driving |
| 2,3,4 | COM | Common Supply Ground |
| 5 | IN _(R) | Signal Input for Low-side R-phase IGBT |
| 6 | V _{FO} | Fault Output |
| 7 | C _{FOD} | Capacitor for Fault Output Duration Time Selection |
| 8 | C _{SC} | Capacitor (Low-pass Filter) for Over Current Detection |
| 9 | R _(TH) | NTC Thermistor terminal |
| 10 | V _(TH) | NTC Thermistor terminal |
| 11,12 | N.C | No Connection* |
| 13~16 | N | IGBT emitter |
| 17~20 | N _R | Negative DC-Link of Rectifier |
| 21,22 | P | Positive Rail of DC-Link |
| 23 | N.C | No Connection |
| 24 | L | Reactor connection pin |
| 25 | P _R | Positive DC-Link of Rectifier |
| 26 | R | AC input for R-phase |
| 27 | S | AC input for S-phase |

* 11th and 12th pins are cut. Please refer to package outline drawings for more detail.

Internal Equivalent Circuit and Input/Output Pins

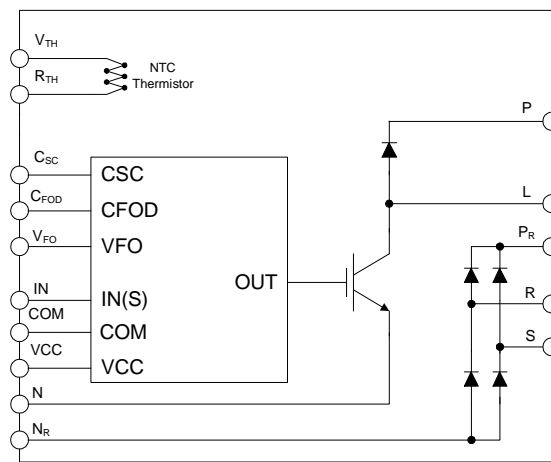


Fig. 3.

Absolute Maximum Ratings ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified)

Converter Part

| Item | Symbol | Condition | Rating | Unit |
|--------------------------------|-----------------|---|-----------|------------------|
| Supply Voltage | V_i | Applied between R-S | 264 | V_{RMS} |
| Supply Voltage (Surge) | $V_{i(Surge)}$ | Applied between R-S | 500 | V |
| Output Voltage | V_{PN} | Applied between P- N | 450 | V |
| Output Voltage (Surge) | $V_{PN(Surge)}$ | Applied between P- N | 500 | V |
| Collector-emitter Voltage | V_{CES} | | 600 | V |
| Peak Forward Surge Current | I_{FSM} | Single half sine-wave | 250 | A |
| Input Current (100% Load) | I_i | $T_C < 95^\circ\text{C}$, $V_i = 220\text{ V}$, $V_{PN} = 390\text{ V}$, $V_{PWM} = 20\text{ kHz}$ | 25 | A |
| Input Current (125% Load) | $I_{i(125\%)}$ | $T_C < 95^\circ\text{C}$, $V_i = 220\text{ V}$, $V_{PN} = 390\text{ V}$, $V_{PWM} = 20\text{ kHz}$, 1 min Non-repetitive | 30 | A |
| Collector Dissipation | P_C | $T_C = 25^\circ\text{C}$ per One IGBT | 169 | W |
| Operating Junction Temperature | T_J | (Note 1) | -20 ~ 150 | $^\circ\text{C}$ |

Note

1. The maximum junction temperature rating of the power chips integrated within the PFC SPM® product is 150°C ($@T_C \leq 100^\circ\text{C}$). However, to insure safe operation of the PFC SPM product, the average junction temperature should be limited to $T_{J(ave)} \leq 125^\circ\text{C}$ ($@T_C \leq 100^\circ\text{C}$)

Control Part

| Item | Symbol | Condition | Rating | Unit |
|-------------------------------|----------|--------------------------------|--------------------|------|
| Control Supply Voltage | V_{CC} | Applied between V_{CC} - COM | 20 | V |
| Input Signal Voltage | V_{IN} | Applied between IN - COM | -0.3~5.5 | V |
| Fault Output Supply Voltage | V_{FO} | Applied between V_{FO} - COM | -0.3- $V_{CC}+0.3$ | V |
| Fault Output Current | I_{FO} | Sink Current at V_{FO} Pin | 5 | mA |
| Current Sensing Input Voltage | V_{SC} | Applied between C_{SC} - COM | -0.3- $V_{CC}+0.3$ | V |

Total System

| Item | Symbol | Condition | Rating | Unit |
|-----------------------------------|-----------|---|-----------|------------------|
| Module Case Operation Temperature | T_C | | -20 ~ 100 | $^\circ\text{C}$ |
| Storage Temperature | T_{STG} | | -40 ~ 125 | $^\circ\text{C}$ |
| Isolation Voltage | V_{ISO} | 60 Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC | 2500 | V_{rms} |

Thermal Resistance

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit |
|---|--------------------|-----------|------|------|------|--------------------|
| Junction to Case Thermal Resistance (Referenced to PKG center) | $R_{\theta(j-c)Q}$ | IGBT | - | - | 0.74 | $^\circ\text{C/W}$ |
| | $R_{\theta(j-c)F}$ | FRD | - | - | 1.44 | $^\circ\text{C/W}$ |
| | $R_{\theta(j-c)R}$ | Rectifier | - | - | 2.07 | $^\circ\text{C/W}$ |

Note :

2. For the measurement point of case temperature(T_C), please refer to Fig. 2.

Electrical Characteristics (T_J = 25°C, Unless Otherwise Specified)

Converter Part

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit |
|-------------------------------------|----------------------|---|------|------|------|------|
| IGBT saturation voltage | V _{CE(sat)} | V _{CC} = 15 V, V _{IN} = 5 V; I _C = 30 A | - | 2.0 | 2.8 | V |
| FRD forward voltage | V _{FF} | I _F = 30 A | - | 1.8 | 2.5 | V |
| Rectifier forward voltage | V _{FR} | I _F = 30 A | - | 1.2 | 1.5 | V |
| Switching Times | t _{ON} | V _{PN} = 400 V, V _{CC} = 15 V, I _C = 30 A V _{IN} = 0 V ↔ 5 V, Inductive Load (Note 3) | - | 650 | - | ns |
| | t _{C(ON)} | | - | 400 | - | ns |
| | t _{OFF} | | - | 620 | - | ns |
| | t _{C(OFF)} | | - | 200 | - | ns |
| | t _{rr} | | - | 60 | - | ns |
| | I _{rr} | | - | 3.5 | - | A |
| Collector - emitter Leakage Current | I _{CES} | V _{CE} = V _{CES} | - | - | 250 | μA |

Note

3. t_{ON} and t_{OFF} include the propagation delay time of the internal drive IC. t_{C(ON)} and t_{C(OFF)} are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

Control Part

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--|----------------------|---|------|------|------|------|
| Quiescent V _{CC} Supply Current | I _{QCCL} | V _{CC} = 15 V, I _N = 0 V V _{CC} - COM | - | - | 26 | mA |
| Fault Output Voltage | V _{FOH} | V _{SC} = 0 V, V _{FO} Circuit: 4.7 kΩ to 5 V Pull-up | 4.5 | - | - | V |
| | V _{FOL} | V _{SC} = 1 V, V _{FO} Circuit: 4.7 kΩ to 5 V Pull-up | - | - | 0.8 | V |
| Over Current Trip Level | V _{SC(ref)} | V _{CC} = 15 V | 0.45 | 0.5 | 0.55 | V |
| Supply Circuit Under-Voltage Protection | UV _{CCD} | Detection Level | 10.7 | 11.9 | 13.0 | V |
| | UV _{CCR} | Reset Level | 11.2 | 12.4 | 13.2 | V |
| Fault-out Pulse Width | t _{FOD} | C _{FOD} = 33 nF (Note 4) | 1.4 | 1.8 | 2.0 | ms |
| ON Threshold Voltage | V _{IN(ON)} | Applied between IN - COM | 2.8 | - | - | V |
| OFF Threshold Voltage | V _{IN(OFF)} | | - | - | 0.8 | V |
| Resistance of Thermistor | R _{TH} | @ T _C = 25°C (Note Fig. 9) | - | 50 | - | kΩ |
| | | @ T _C = 100°C (Note Fig. 9) | - | 2.99 | - | kΩ |

Note

4. The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation : C_{FOD} = 18.3 x 10⁻⁶ x t_{FOD}[F]

Electrical Characteristics

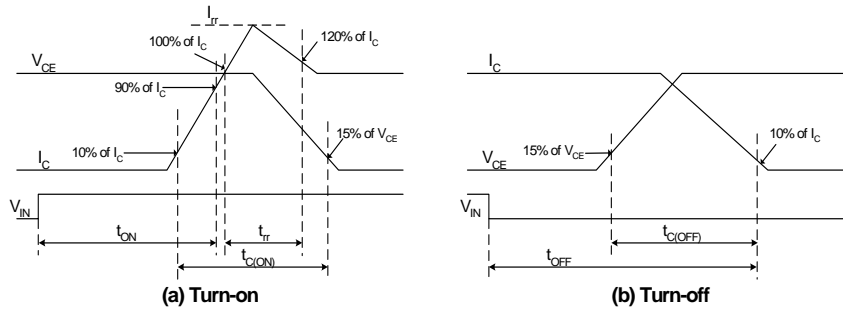


Fig. 4. Switching Time Definition

Mechanical Characteristics and Ratings

| Item | Condition | Limits | | | Units | | |
|-----------------|--------------------|----------------------|-------|------|-------|------|-----|
| | | Min. | Typ. | Max. | | | |
| Mounting Torque | Mounting Screw: M3 | Recommended 0.62 N•m | | 0.51 | 0.62 | 0.72 | N•m |
| Device Flatness | Note Fig. 5 | 0 | - | +120 | | | μm |
| Weight | | - | 15.00 | - | | | g |

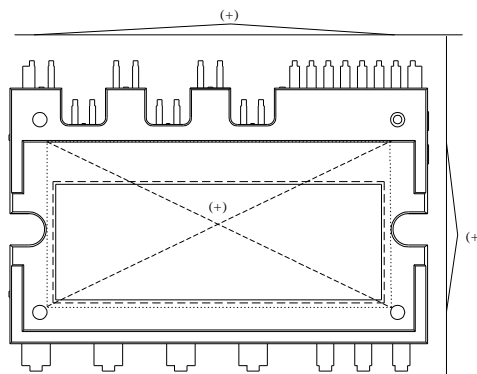
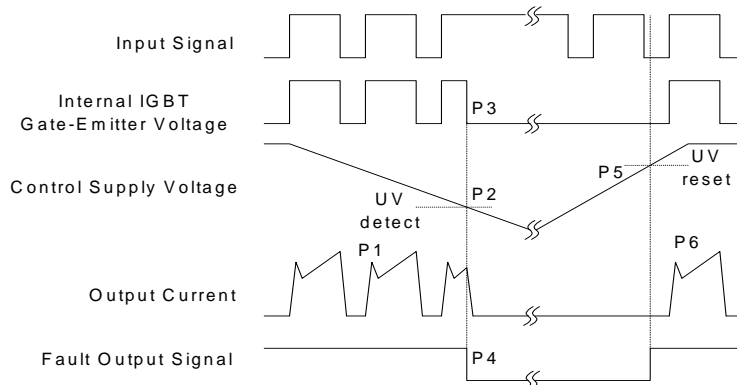


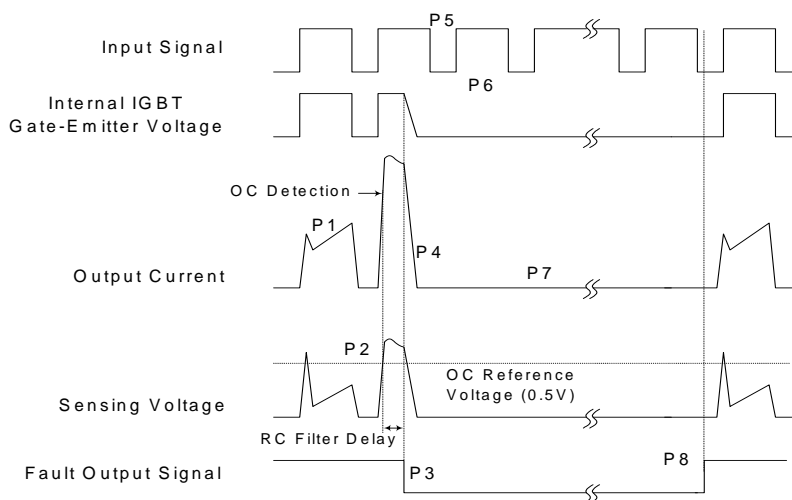
Fig. 5. Flatness Measurement Position

Time Charts of SPMs Protective Function



- P1 : Normal operation - IGBT ON and conducting current
- P2 : Under voltage detection
- P3 : IGBT gate interrupt
- P4 : Fault signal generation
- P5 : Under voltage reset
- P6 : Normal operation - IGBT ON and conducting current

Fig. 6. Under-Voltage Protection



- P1 : Normal operation - IGBT ON and conducting current
- P2 : Over current detection
- P3 : IGBT gate interrupt / Fault signal generation
- P4 : IGBT is slowly turned off
- P5 : IGBT OFF signal
- P6 : IGBT ON signal - but IGBT cannot be turned on during the fault Output activation
- P7 : IGBT OFF state
- P8 : Fault Output reset and normal operation start

Fig. 7. Over Current Protection

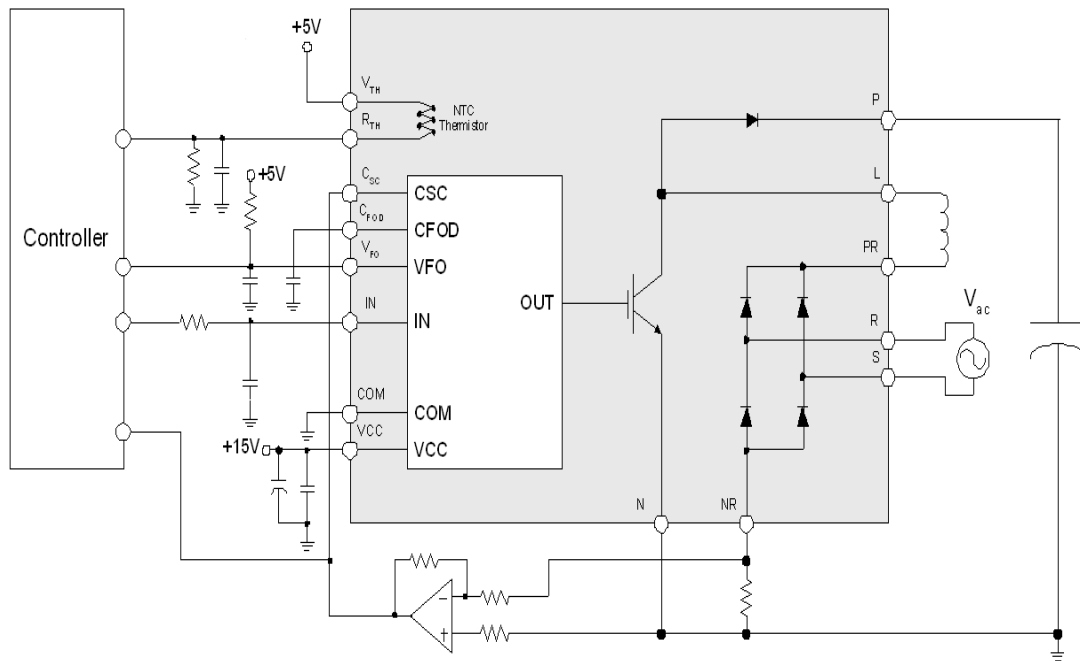


Fig. 8. Application Example

R-T Graph

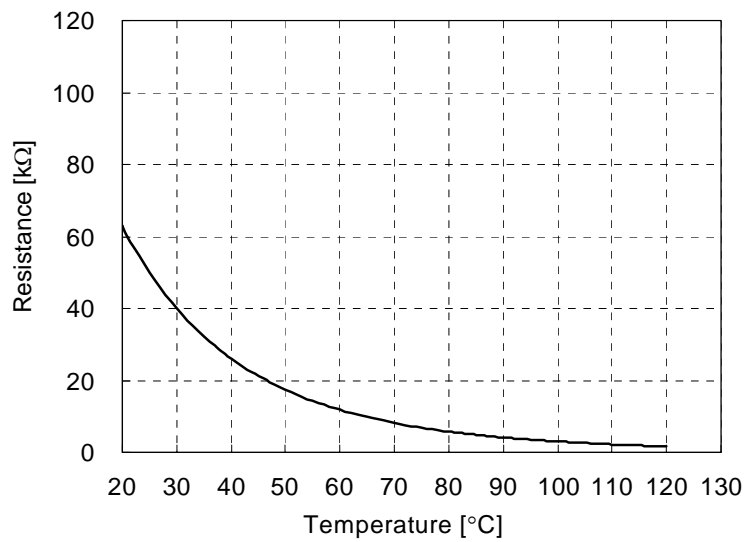
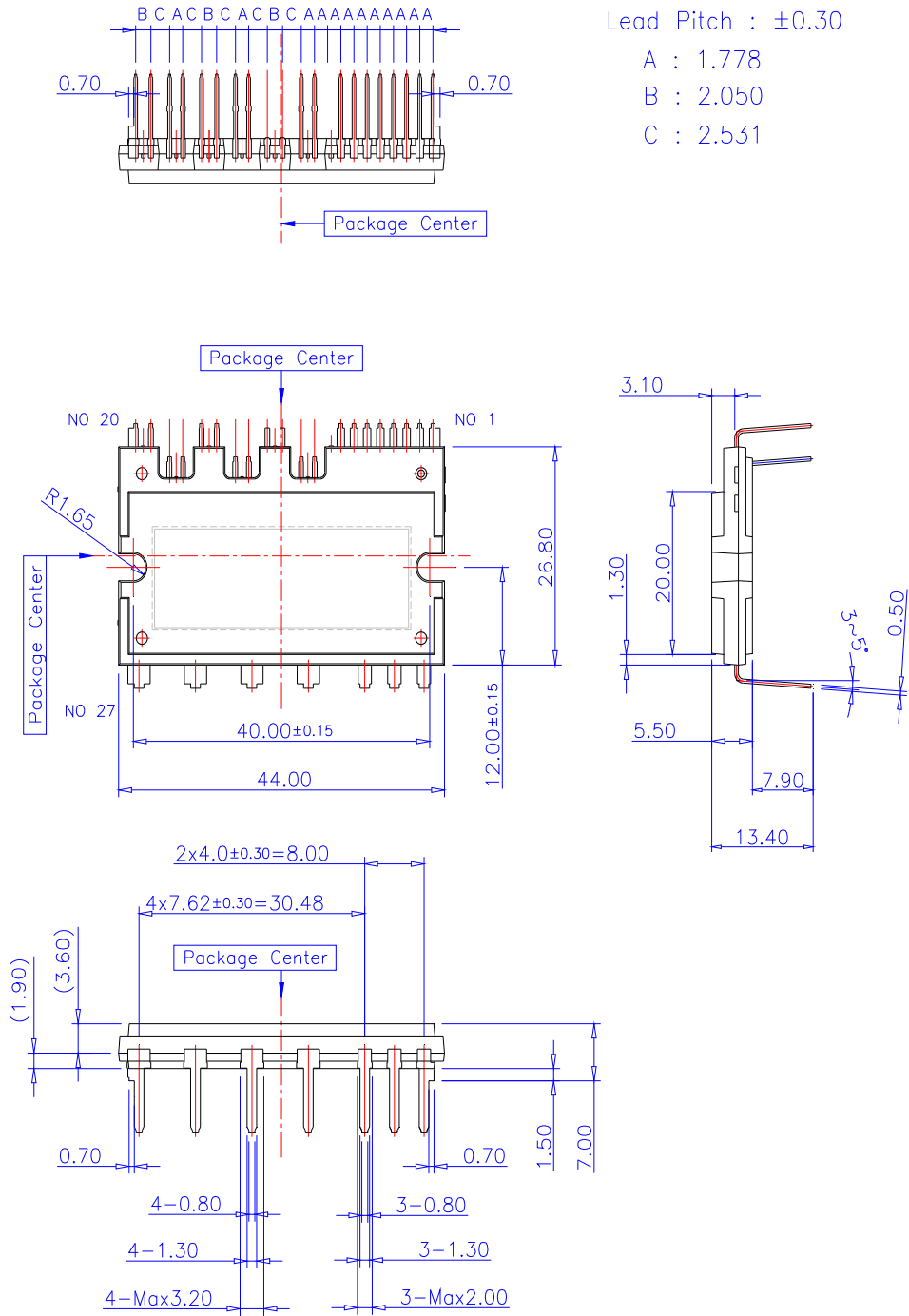
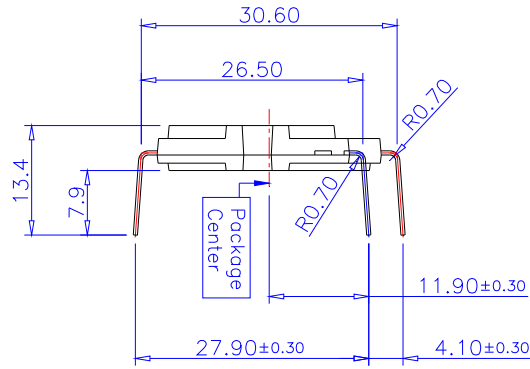


Fig. 9. R-T Curve of the Built-in Thermistor

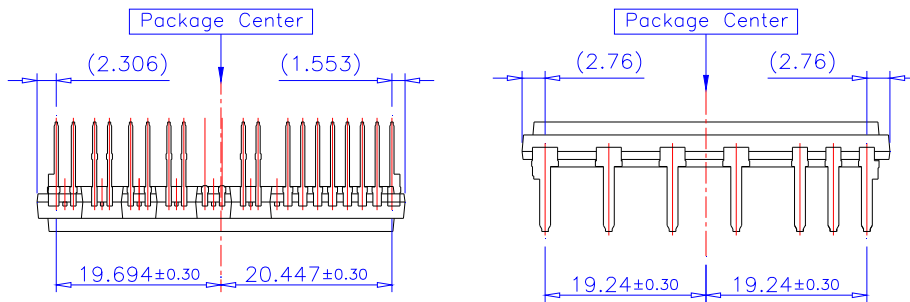
Detailed Package Outline Drawings



Detailed Package Outline Drawings

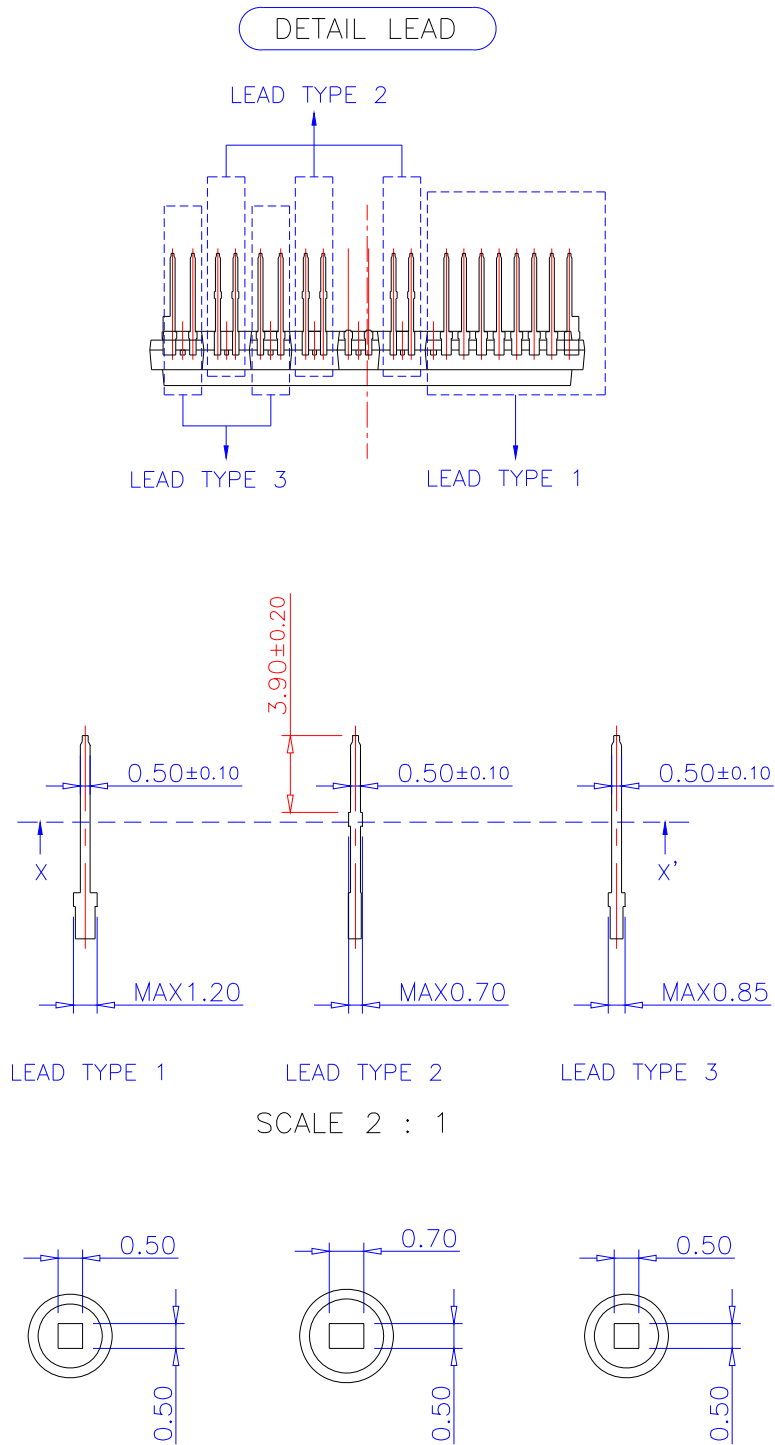


Lead Forming Dimension



PKG Center to Lead Distance

Detailed Package Outline Drawings





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Rev. I64